

**TRIPLE DIFFUSED PLANER TYPE  
HIGH VOLTAGE,HIGH SPEED SWITCHING**

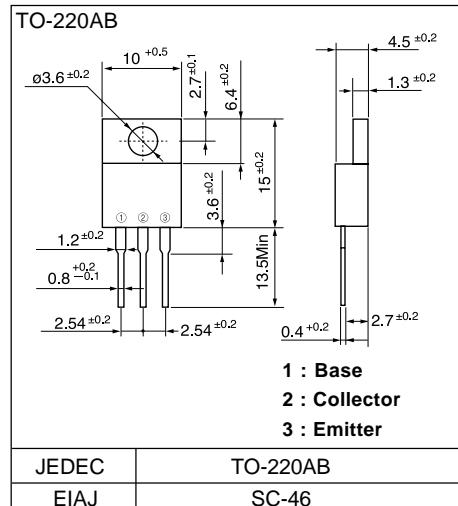
**■ Features**

- High voltage,High speed switching
- Low saturation voltage
- High reliability

**■ Applications**

- Switching regulators
- DC-DC convertor
- Solid state relay
- General purpose power amplifiers

**■ Outline Drawings**



**■ Maximum ratings and characteristics**

**● Absolute maximum ratings ( $T_c=25^\circ\text{C}$  unless otherwise specified)**

Item	Symbol	Ratings	Unit
Collector-Base voltage	$V_{CBO}$	450	V
Collector-Emitter voltage	$V_{CEO}$	400	V
Emitter-Base voltage	$V_{EBO}$	10	V
Collector current	$I_C$	7	A
Base current	$I_B$	2	A
Collector power dissipation	$P_C$	40	W
Operating junction temperature	$T_J$	+150	°C
Storage temperature	$T_{Stg}$	-55 to +150	°C

**● Electrical characteristics ( $T_c = 25^\circ\text{C}$  unless otherwise specified)**

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	$V_{CBO}$	$I_{CBO} = 1\text{mA}$	450			V
Collector-Emitter voltage	$V_{CEO}$	$I_{CEO} = 0.2\text{A}$	400			V
Emitter-Base voltage	$V_{EBO}$	$I_{EBO} = 1\text{mA}$	10	-		V
Collector-Base leakage current	$I_{CBO}$	$V_{CBO} = 450\text{V}$		-	0.1	mA
Emitter-Base leakage current	$I_{EBO}$	$V_{EBO} = 10\text{V}$		-	0.1	mA
D.C. current gain	$h_{FE}$	$I_C = 4\text{A}, V_{CE} = 5\text{V}$	10			
Collector-Emitter saturation voltage	$V_{CE(Sat)}$	$I_C = 4\text{A}, I_B = 800\text{mA}$			0.8	V
Base-Emitter saturation voltage	$V_{BE(Sat)}$				1.2	V
*1	$t_{on}$	$I_C = 5\text{A}, I_B1 = 1\text{A}$ $I_B2 = -2\text{A}, R_L = 30 \Omega$ $P_w = 20\mu\text{s} \text{ Duty} = <2\%$			1.0	μs
Switching time	$t_{stg}$				2.5	μs
	$t_f$				0.5	μs

**● Thermal characteristics**

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	$R_{th(j-c)}$	Junction to case			3.0	°C/W

## ■ Characteristics

